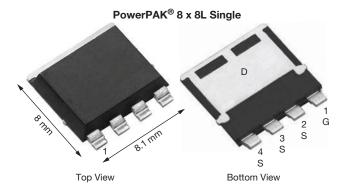
## SQJQ480E



**Vishay Siliconix** 

# Automotive N-Channel 80 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	80				
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.003				
I <sub>D</sub> (A)	150				
Configuration	Single				
Package	PowerPAK 8 x 8L				



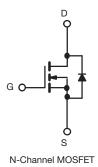
### FEATURES

- TrenchFET<sup>®</sup> power MOSFET
- AEC-Q101 qualified
- 100 % R<sub>q</sub> and UIS tested
- Fully lead (Pb)-free device
- Thin 1.9 mm height
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



HALOGEN

FREE



<b>ABSOLUTE MAXIMUM RATIN</b>	<b>GS</b> (T <sub>C</sub> = 25 °C, unless	otherwise noted	)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V <sub>DS</sub>	80	M	
Gate-Source Voltage		V <sub>GS</sub>	± 20	V	
Continuous Drain Current	T <sub>C</sub> = 25 °C		150		
Continuous Drain Current	T <sub>C</sub> = 125 °C	I <sub>D</sub>	87		
Continuous Source Current (Diode conduction)		I <sub>S</sub>	124	А	
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	210		
Single Pulse Avalanche Current		I <sub>AS</sub>	53		
Single Pulse Avalanche Energy	L = 0.1 mH	E <sub>AS</sub>	140	mJ	
Maximum Bower Dissipation	T <sub>C</sub> = 25 °C	D	136	W	
Maximum Power Dissipation	T <sub>C</sub> = 125 °C	P <sub>D</sub>	45	vv	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	*0	
Soldering Recommendations (Peak temperature) <sup>c, d</sup>			260	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB mount <sup>b</sup>	R <sub>thJA</sub>	50	°C/W
Junction-to-Case (Drain)		R <sub>thJC</sub>	1.1	C/ W

#### Notes

- a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.
- b. When mounted on 1" square PCB (FR4 material).

c. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK 8 x 8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

d. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

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SQJQ480E

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static	•	•					
Drain-Source Breakdown Voltage	V <sub>DS</sub>	V <sub>GS</sub>	= 0, I <sub>D</sub> = 250 μA	80	-	-	V
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	· V <sub>GS</sub> , I <sub>D</sub> = 250 μA	2.5	3	3.5	v
Gate-Source Leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	0 V, $V_{GS} = \pm 20 V$	-	-	± 100	nA
		$V_{GS} = 0 V$	V <sub>DS</sub> = 80 V	-	-	1	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = 80 V, T <sub>J</sub> = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	$V_{DS} = 80 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	500	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	50	-	-	Α
		$V_{GS} = 10 V$	I <sub>D</sub> = 20 A	-	0.0024	0.0030	- V   3.5 V   ± 100 nA   1 μA   500 -   - A   0.0030 Ω
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 V$	I <sub>D</sub> = 20 A, T <sub>J</sub> = 125 °C	-	-	0.0048	Ω
		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 20 A, T <sub>J</sub> = 175 °C	-	-	0.0060	
Forward Transconductance b	9 <sub>fs</sub>	V <sub>DS</sub>	= 15 V, I <sub>D</sub> = 15 A	-	82	-	S
Dynamic <sup>b</sup>							
Input Capacitance	C <sub>iss</sub>			-	6900	8625	
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = 25 V, f = 1 MHz	-	3655	4570	рF
Reverse Transfer Capacitance	C <sub>rss</sub>			-	250	311	
Total Gate Charge <sup>c</sup>	Qg			-	82	144	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{GS} = 10 V$	$V_{DS} = 40 \text{ V}, \text{ I}_{D} = 10 \text{ A}$	-	11	-	nC
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			-	21	-	
Gate Resistance	R <sub>g</sub>		f = 1 MHz	0.4	0.8	1.2	Ω
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			-	19	30	
Rise Time <sup>c</sup>	t <sub>r</sub>	V <sub>DD</sub>	= 40 V, $R_{L}$ = 4 $\Omega$	-	7.3	11	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong 10 \text{ A},$	$V_{GEN} = 10 \text{ V}, \text{ R}_{g} = 1 \Omega$	-	40	60	ns
Fall Time <sup>c</sup>	t <sub>f</sub>			-	15	23	
Source-Drain Diode Ratings and Cha	racteristics <sup>b</sup>						
Pulsed Current <sup>a</sup>	I <sub>SM</sub>			-	-	210	Α
Forward Voltage	V <sub>SD</sub>	I <sub>F</sub> = 40 A, V <sub>GS</sub> = 0 V		_	0.7	1.2	V

#### Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

www.vishay.com

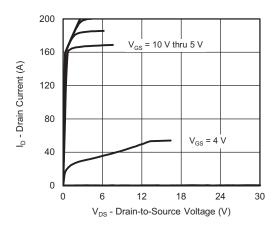
b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

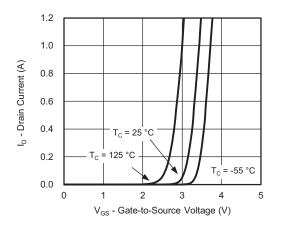
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



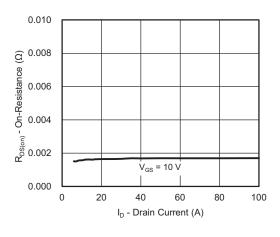
## **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



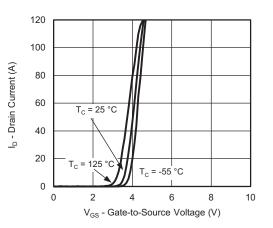
**Output Characteristics** 



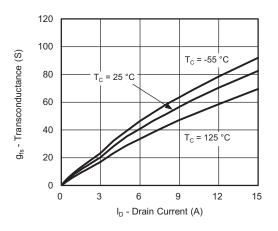
**Transfer Characteristics** 



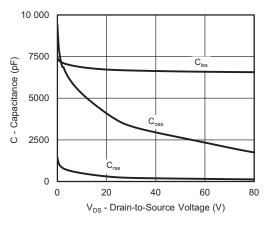
**On-Resistance vs. Drain Current** 



**Transfer Characteristics** 



Transconductance



#### Capacitance

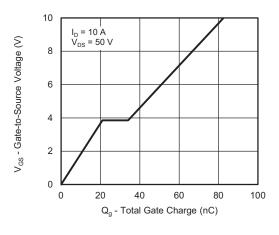
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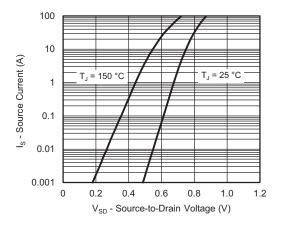
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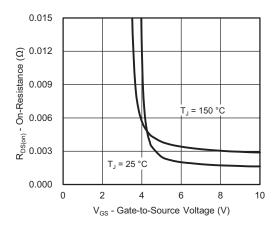
## TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



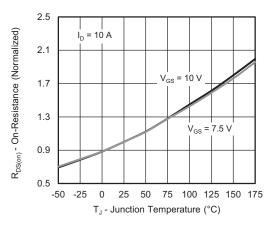
Gate Charge



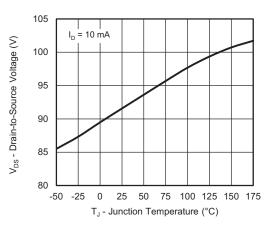
Source Drain Diode Forward Voltage



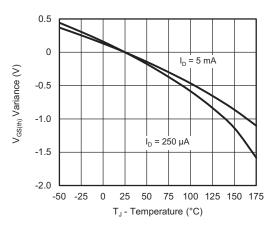
**On-Resistance vs. Gate-to-Source Voltage** 



**On-Resistance vs. Junction Temperature** 



Drain Source Breakdown vs. Junction Temperature



#### **Threshold Voltage**

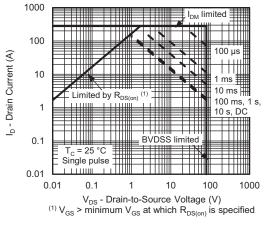
S16-1373-Rev. A, 11-Jul-16

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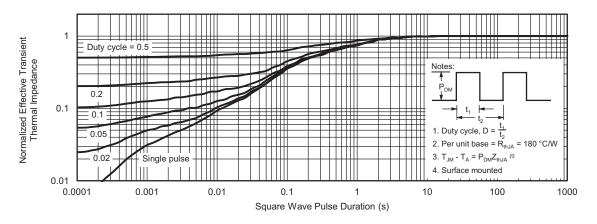


## **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



Safe Operating Area

**THERMAL RATINGS** ( $T_A = 25$  °C, unless otherwise noted)



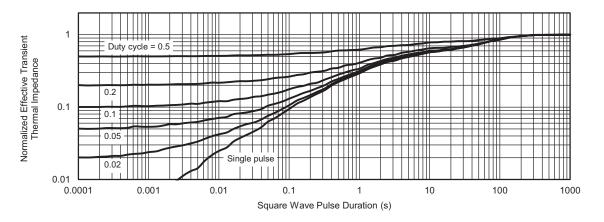
Normalized Thermal Transient Impedance, Junction-to-Ambient



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## THERMAL RATINGS (T<sub>A</sub> = 25 °C, unless otherwise noted)



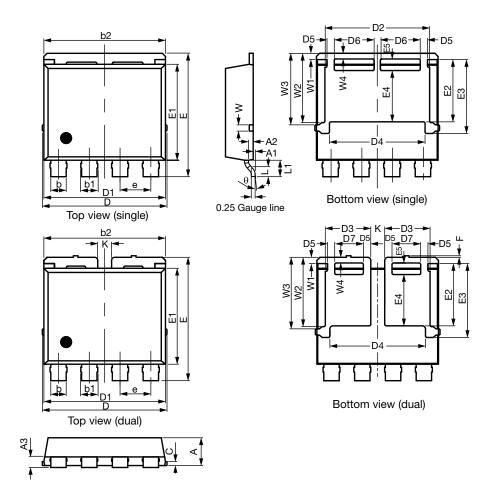
Normalized Thermal Transient Impedance, Junction-to-Case

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DIM.		MILLIMETERS		INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	1.70	1.80	1.90	0.067	0.071	0.075	
A1	0.00	0.08	0.13	0.000	0.003	0.005	
A2	0.25	0.30	0.35	0.010	0.012	0.014	
A3	0.55	0.62	0.70	0.022	0.024	0.028	
b	0.92	1.00	1.08	0.036	0.039	0.043	
b1	1.02	1.10	1.18	0.040	0.043	0.046	
b2	7.80	7.90	8.00	0.307	0.311	0.315	
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	8.00	8.10	8.25	0.315	0.319	0.325	
D1	7.80	7.90	8.00	0.307	0.311	0.315	
D2	6.70	6.80	6.90	0.264	0.268	0.272	
D3	2.85	2.95	3.05	0.112	0.116	0.120	
D4	6.11	6.21	6.31	0.241	0.244	0.248	
D5	0.37	0.47	0.57	0.015	0.019	0.022	
D6	2.49	2.59	2.69	0.098	0.102	0.106	
D7	1.76	1.86	1.96	0.069	0.073	0.077	

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Document Number: 67734

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# **Package Information**



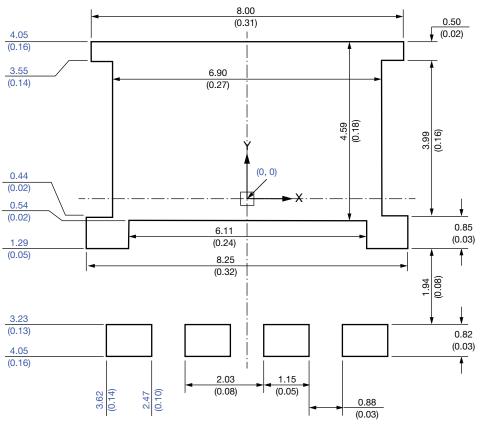


## Vishay Siliconix

DIM.		MILLIMETERS		INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
е	1.95	2.00	2.05	0.077	0.079	0.081	
Е	7.90	8.00	8.10	0.311	0.315	0.319	
E1	6.12	6.22	6.32	0.241	0.245	0.249	
E2	3.94	4.04	4.14	0.140	0.159	0.163	
E3	4.69	4.79	4.89	0.185	0.189	0.193	
E4	3.23	3.33	3.43	0.127	0.131	0.135	
E5	0.65	0.75	0.85	0.026	0.030	0.033	
F	0.00	0.10	0.15	0.000	0.004	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
К	0.80	0.90	1.00	0.031	0.035	0.039	
W	0.30	0.40	0.50	0.012	0.016	0.020	
W1	0.30	0.40	0.50	0.012	0.016	0.020	
W2	4.39	4.49	4.59	0.173	0.177	0.181	
W3	4.54	4.64	4.74	0.179	0.183	0.187	
W4	0.32	0.37	0.42	0.013	0.015	0.017	
θ	6°	10°	14°	6°	10°	14°	



# **Recommended Minimum PADs for PowerPAK® 8 x 8L Single**



Dimensions in millimeters (inches)

#### Note

• Linear dimensions are in black, the same information is provided in ordinate dimensions which are in blue.



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